



UTT6NP10

Power MOSFET

DUAL ENHANCEMENT MODE (N-CHANNEL/P-CHANNEL)

DESCRIPTION

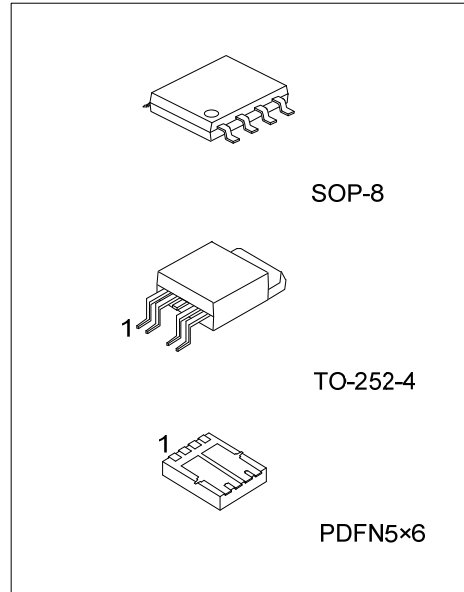
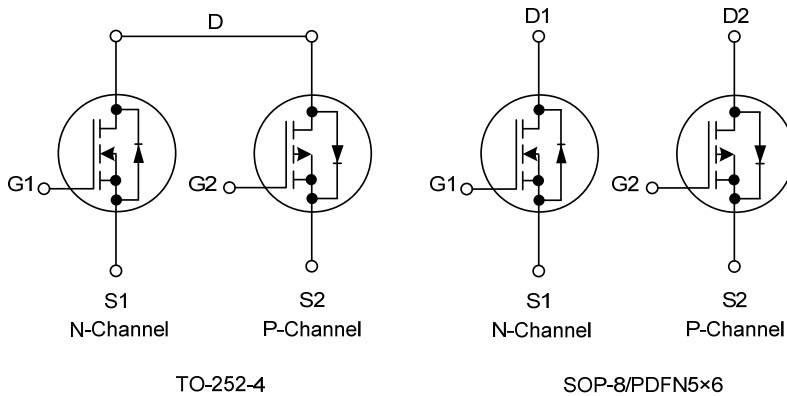
The UTC **UTT6NP10** incorporates an N-channel MOSFET and a P-channel MOSFET, it uses UTC's advanced technology to provide customers a minimum on-state resistance and high-speed switching, thereby enabling high-density mounting.

The UTC **UTT6NP10** is universally applied in high-speed switching, motor driver.

FEATURES

- * $R_{DS(on)} \leq 150 \text{ m}\Omega @ V_{GS}=10\text{V}, I_D=3.0\text{A}$
- $R_{DS(on)} \leq 200 \text{ m}\Omega @ V_{GS}=4.5\text{V}, I_D=3.0\text{A}$
- * $R_{DS(on)} \leq 155 \text{ m}\Omega @ V_{GS}=-10\text{V}, I_D=-3.0\text{A}$
- $R_{DS(on)} \leq 210 \text{ m}\Omega @ V_{GS}=-4.5\text{V}, I_D=-3.0\text{A}$
- * High switching speed

SYMBOL



ORDERING INFORMATION

| Ordering Number | | Package | Pin Assignment | | | | | | | | Packing |
|-------------------|-------------------|----------|----------------|----|----|----|----|----|----|----|-----------|
| Lead Free | Halogen Free | | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | |
| UTT6NP10L-TN4-R | UTT6NP10G-TN4-R | TO-252-4 | S1 | G1 | D | S2 | G2 | - | - | - | Tape Reel |
| UTT6NP10L-S08-R | UTT6NP10G-S08-R | SOP-8 | S1 | G1 | S2 | G2 | D2 | D2 | D1 | D1 | Tape Reel |
| UTT6NP10L-P5060-R | UTT6NP10G-P5060-R | PDFN5x6 | S1 | G1 | S2 | G2 | D2 | D2 | D1 | D1 | Tape Reel |

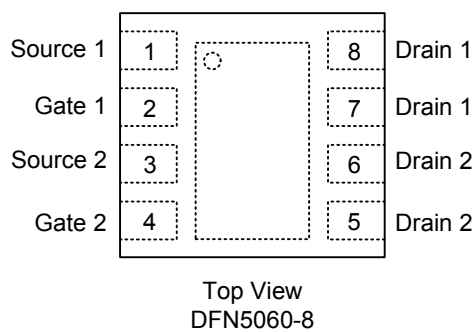
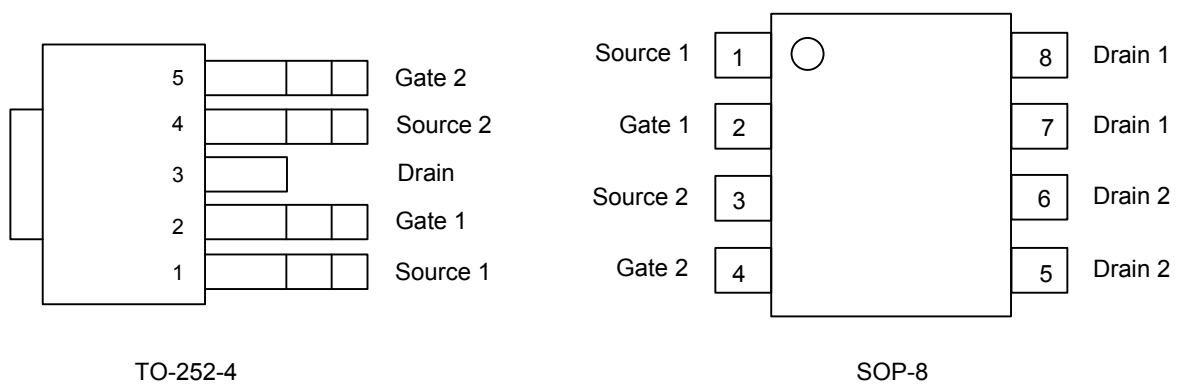
Note: Pin Assignment: G: Gate D: Drain S: Source

| | |
|--|--|
| <p>UTT6NP10G-TN4-R</p> <ul style="list-style-type: none"> (1) Packing Type (2) Package Type (3) Green Package | <ul style="list-style-type: none"> (1) R: Tape Reel (2) TN4: TO-252-4, S08: SOP-8, P5060: PDFN5x6 (3) G: Halogen Free and Lead Free, L: Lead Free |
|--|--|

MARKING

| PACKAGE | MARKING |
|----------|--|
| TO-252-4 | <p>UTC UTT6NP10 Lot Code → → → → → Date Code</p> <p>L: Lead Free G: Halogen Free</p> |
| SOP-8 | <p>UTC UTT6NP10 Date Code L: Lead Free G: Halogen Free Lot Code</p> |
| PDFN5x6 | <p>UTC UTT 6NP10 Lot Code → → → → → Date Code</p> |

PIN CONFIGURATION



■ ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$, unless otherwise specified)

| PARAMETER | | SYMBOL | RATINGS | | UNIT |
|--|---------------------|-----------|------------|-----------|------------------|
| | | | N-CHANNEL | P-CHANNEL | |
| Drain-Source Voltage | | V_{DSS} | 100 | -100 | V |
| Gate-Source Voltage | | V_{GSS} | ± 20 | ± 20 | V |
| Drain Current | Continuous (Note 3) | I_D | 6 | -6 | A |
| | Pulsed (Note 1) | I_{DM} | 12 | -12 | A |
| Power Dissipation ($T_A=25^\circ\text{C}$) | TO-252-4 | P_D | 3.1 | | W |
| | SOP-8 | | 1.4 | | W |
| | PDFN5x6 | | 1.9 | | W |
| Junction Temperature | | T_J | -55 ~ +150 | | $^\circ\text{C}$ |
| Storage Temperature Range | | T_{STG} | -55 ~ +150 | | $^\circ\text{C}$ |

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

| PARAMETER | | SYMBOL | RATINGS | UNIT |
|---------------------|----------|---------------|---------|--------------------|
| Junction to Ambient | TO-252-4 | θ_{JA} | 40 | $^\circ\text{C/W}$ |
| | SOP-8 | | 89.3 | $^\circ\text{C/W}$ |
| | PDFN5x6 | | 65 | $^\circ\text{C/W}$ |

Note: Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

■ ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$, unless otherwise specified)

N-channel

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|--------------|--|-----|-----|------|---------------|
| OFF CHARACTERISTICS | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $I_D=250\mu\text{A}, V_{GS}=0\text{V}$ | 100 | | | V |
| Drain-Source Leakage Current | I_{DSS} | $V_{DS}=100\text{V}, V_{GS}=0\text{V}$ | | | 10 | μA |
| Gate-Source Leakage Current | I_{GSS} | Forward $V_{GS}=+20\text{V}$ | | | +100 | nA |
| | | Reverse $V_{GS}=-20\text{V}$ | | | -100 | nA |
| ON CHARACTERISTICS | | | | | | |
| Gate Threshold Voltage | $V_{GS(TH)}$ | $V_{DS}=V_{GS}, I_D=250\mu\text{A}$ | 1.0 | | 3.0 | V |
| Static Drain-Source On-State Resistance (Note 2) | $R_{DS(ON)}$ | $V_{GS}=10\text{V}, I_D=3.0\text{A}$ | | | 150 | m Ω |
| | | $V_{GS}=4.5\text{V}, I_D=3.0\text{A}$ | | | 200 | m Ω |
| DYNAMIC PARAMETERS | | | | | | |
| Input Capacitance | C_{ISS} | $V_{GS}=0\text{V}, V_{DS}=-25\text{V}, f=1.0\text{MHz}$ | | 923 | | pF |
| Output Capacitance | C_{OSS} | | | 54 | | pF |
| Reverse Transfer Capacitance | C_{RSS} | | | 43 | | pF |
| SWITCHING PARAMETERS | | | | | | |
| Total Gate Charge (Note 2) | Q_G | $V_{DS}=50\text{V}, V_{GS}=10\text{V}, I_D=6\text{A}$ (Note 1, 2) | | 23 | | nC |
| Gate to Source Charge | Q_{GS} | | | 3.4 | | nC |
| Gate to Drain Charge | Q_{GD} | | | 4.7 | | nC |
| Turn-ON Delay Time (Note 2) | $t_{D(ON)}$ | $V_{DD}=50\text{V}, V_{GS}=10\text{V},$ $I_D=6\text{A}, R_G=25\Omega$ (Note 1, 2) | | 3.5 | | ns |
| Rise Time | t_R | | | 17 | | ns |
| Turn-OFF Delay Time | $t_{D(OFF)}$ | | | 22 | | ns |
| Fall-Time | t_F | | | 17 | | ns |
| SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS | | | | | | |
| Drain-Source Diode Forward Voltage (Note 2) | V_{SD} | $I_S=6.0\text{A}, V_{GS}=0\text{V}$ | | | 1.3 | V |

■ ELECTRICAL CHARACTERISTICS (Cont.)

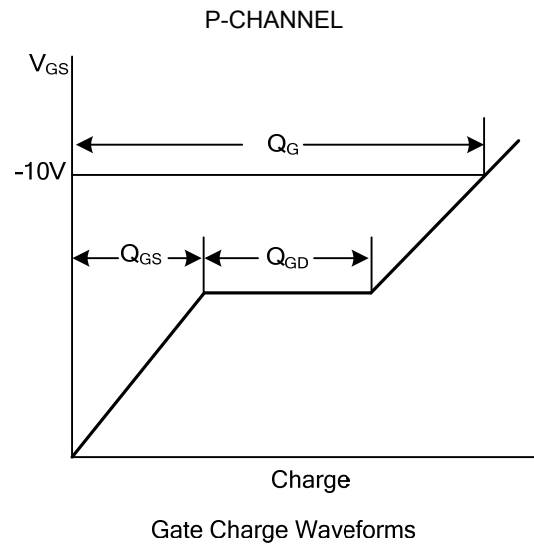
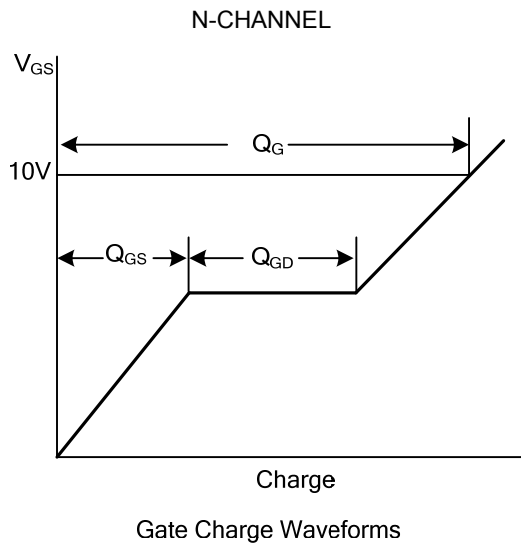
P-Channel

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|--------------|---|------|------|------|------------|
| OFF CHARACTERISTICS | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $I_D = -250\mu A, V_{GS} = 0V$ | -100 | | | V |
| Drain-Source Leakage Current | I_{DSS} | $V_{DS} = -100V, V_{GS} = 0V$ | | | -10 | μA |
| Gate-Source Leakage Current | Forward | $V_{GS} = +20V, V_{DS} = 0V$ | | | +100 | nA |
| | Reverse | $V_{GS} = -20V, V_{DS} = 0V$ | | | -100 | nA |
| ON CHARACTERISTICS | | | | | | |
| Gate Threshold Voltage | $V_{GS(TH)}$ | $V_{DS} = V_{GS}, I_D = -250\mu A$ | -1.0 | | -3.0 | V |
| Static Drain-Source On-State Resistance (Note 2) | $R_{DS(ON)}$ | $V_{GS} = -10V, I_D = -3.0A$ | | | 155 | m Ω |
| | | $V_{GS} = -4.5V, I_D = -3.0A$ | | | 210 | m Ω |
| DYNAMIC PARAMETERS | | | | | | |
| Input Capacitance | C_{ISS} | $V_{GS} = 0V, V_{DS} = -25V, f = 1.0MHz$ | | 1650 | | pF |
| Output Capacitance | C_{OSS} | | | 90 | | pF |
| Reverse Transfer Capacitance | C_{RSS} | | | 62 | | pF |
| SWITCHING PARAMETERS | | | | | | |
| Total Gate Charge (Note 2) | Q_G | $V_{DS} = -50V, V_{GS} = -10V, I_D = -6A$ (Note 1, 2) | | 34 | | nC |
| Gate to Source Charge | Q_{GS} | | | 5.2 | | nC |
| Gate to Drain Charge | Q_{GD} | | | 5.5 | | nC |
| Turn-ON Delay Time (Note 2) | $t_{D(ON)}$ | $V_{DD} = -50V, V_{GS} = -10V,$ $I_D = -6A, R_G = 3.3\Omega$ (Note 1, 2) | | 6.5 | | ns |
| Rise Time | t_R | | | 17 | | ns |
| Turn-OFF Delay Time | $t_{D(OFF)}$ | | | 37 | | ns |
| Fall-Time | t_F | | | 19 | | ns |
| SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS | | | | | | |
| Drain-Source Diode Forward Voltage(Note 2) | V_{SD} | $I_S = -6.0A, V_{GS} = 0V$ | | | -1.3 | V |

Notes: 1. Pulse Test: Pulse width limited by Max. junction temperature.

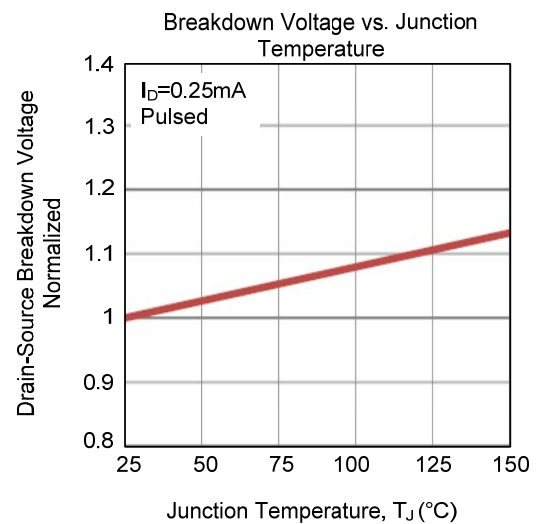
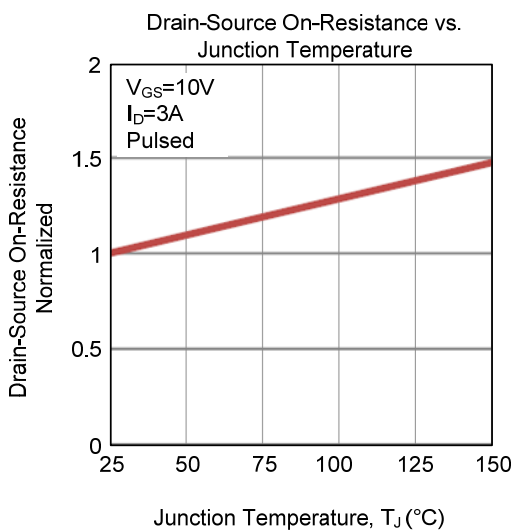
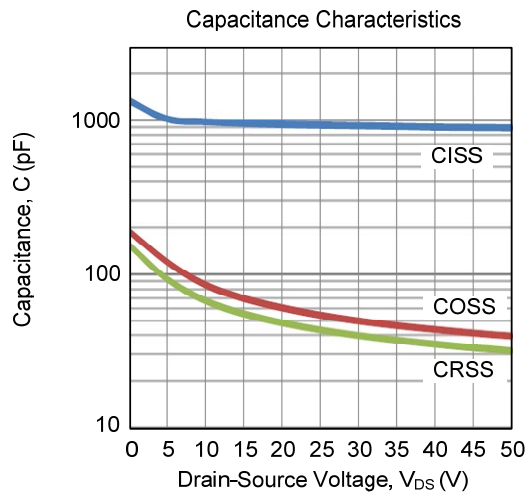
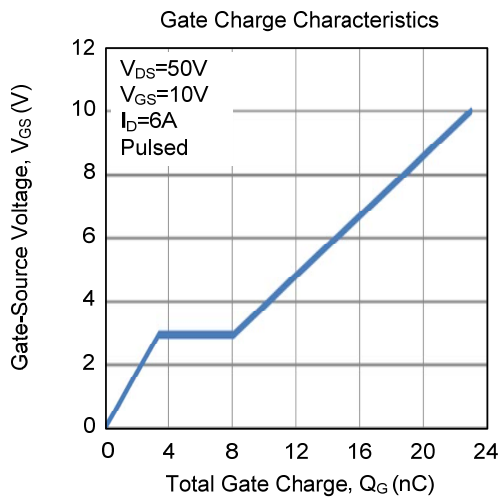
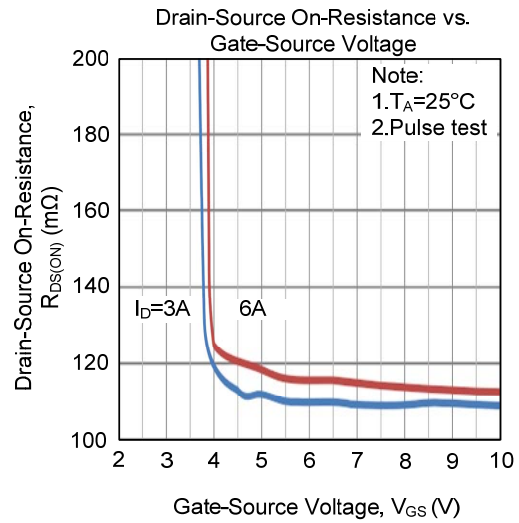
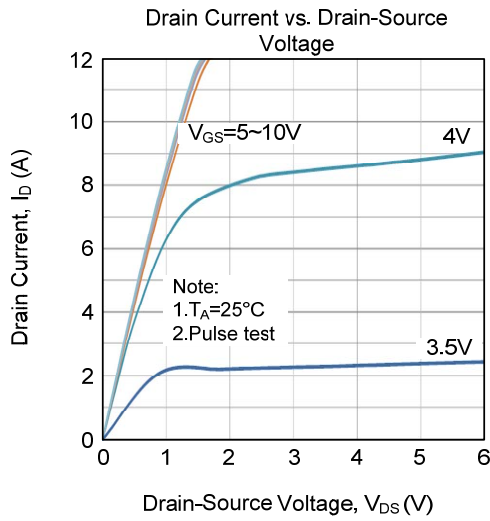
2. N-CH, P-CH are same, mounted on 2oz FR4 board $t \leq 10s$.

■ TEST CIRCUITS AND WAVEFORMS



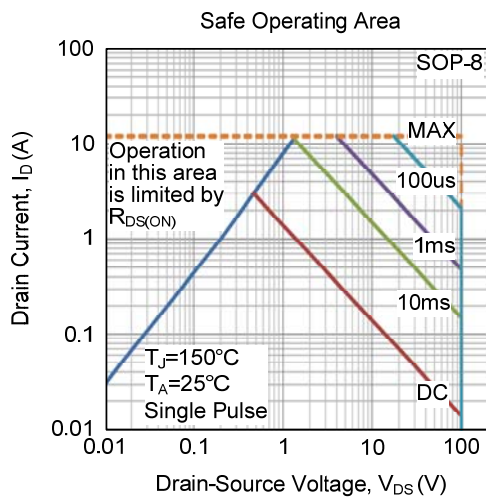
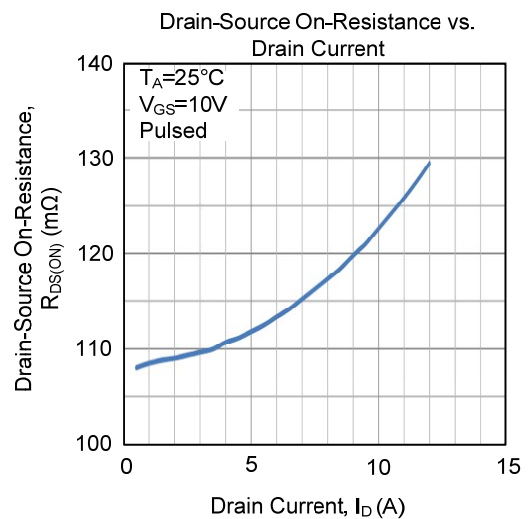
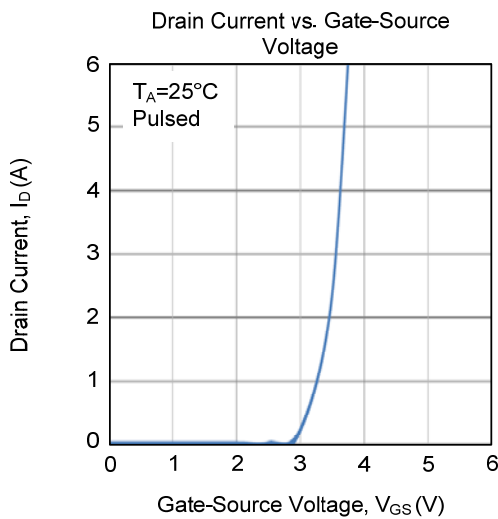
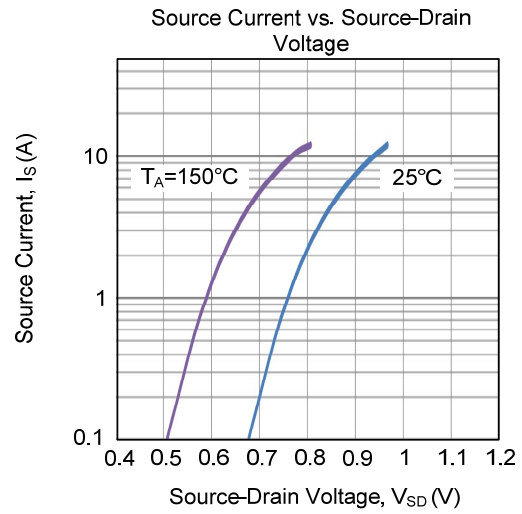
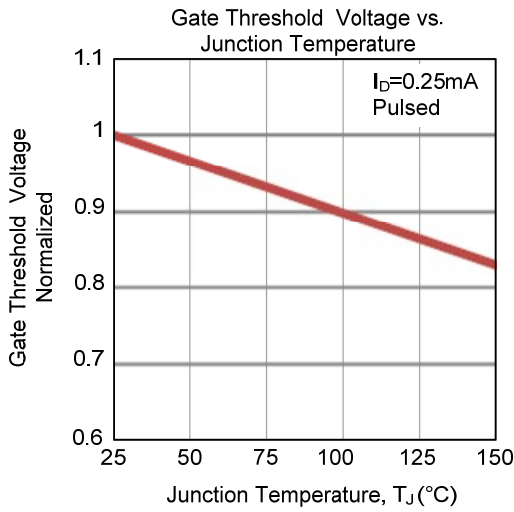
TYPICAL CHARACTERISTICS

N-CHANNEL



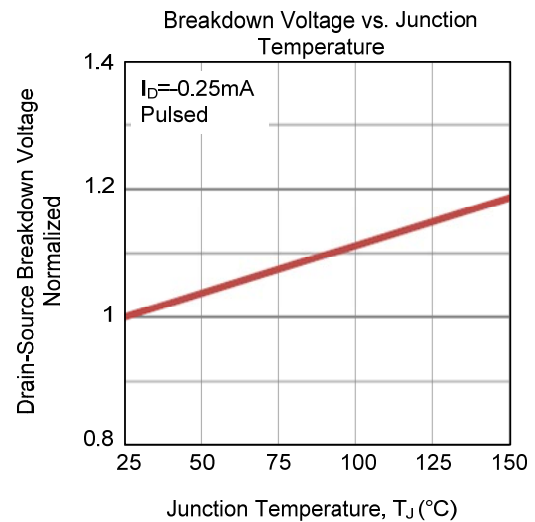
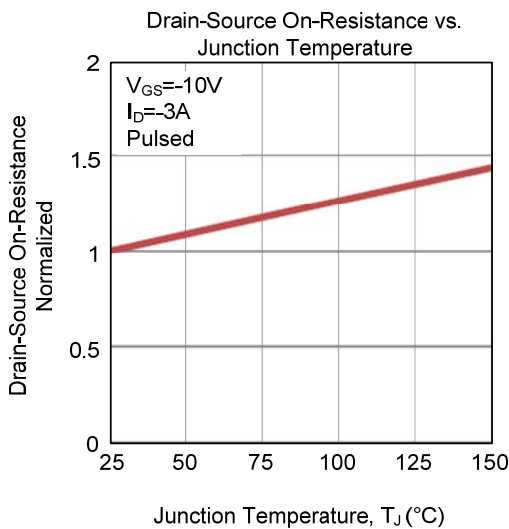
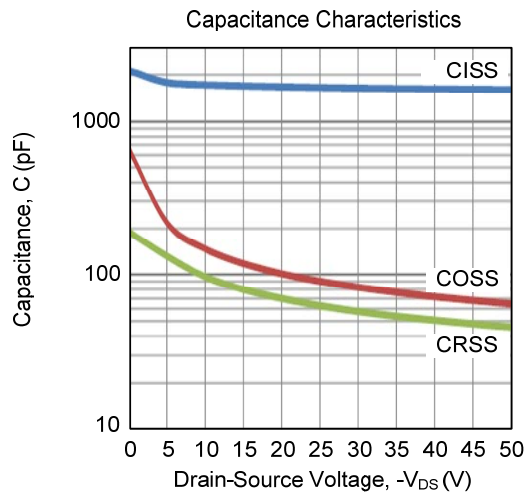
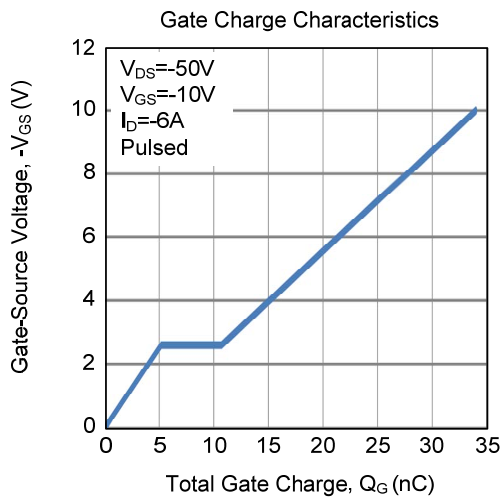
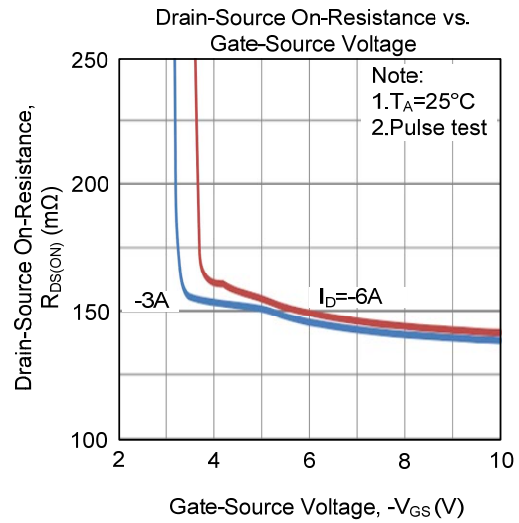
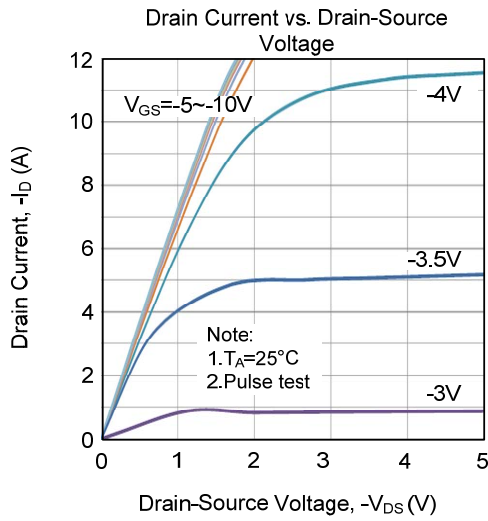
■ TYPICAL CHARACTERISTICS (Cont.)

N-CHANNEL



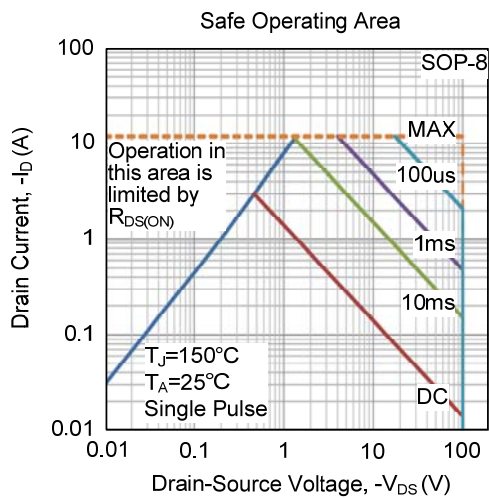
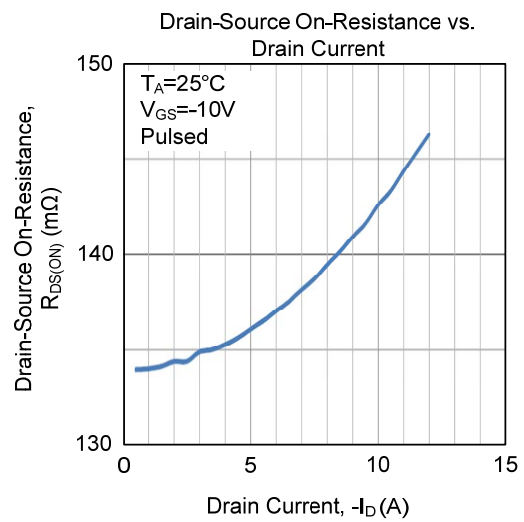
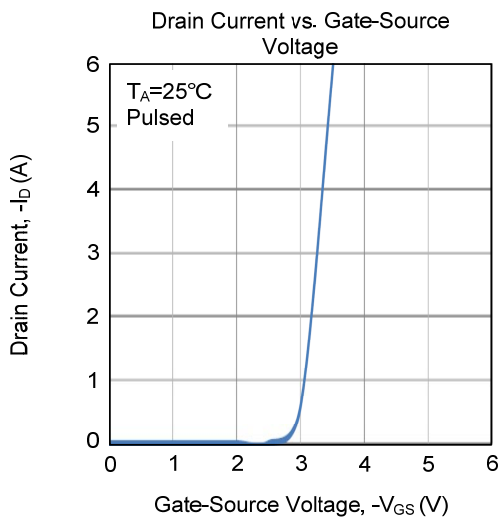
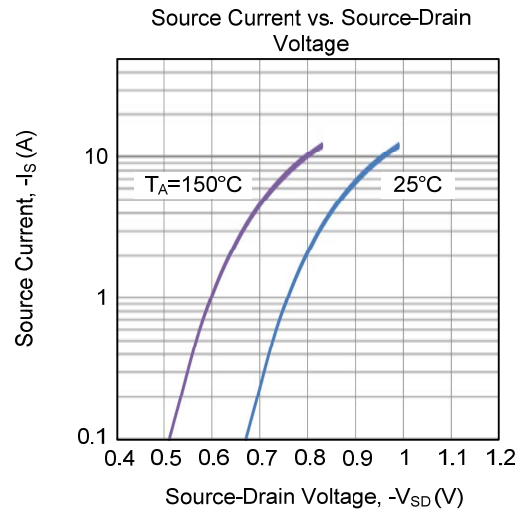
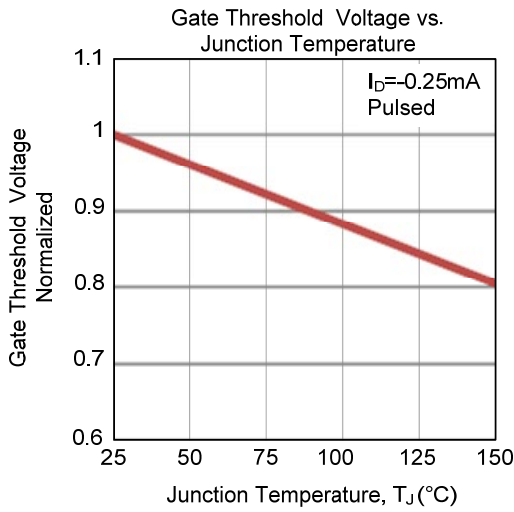
TYPICAL CHARACTERISTICS (Cont.)

P-CHANNEL

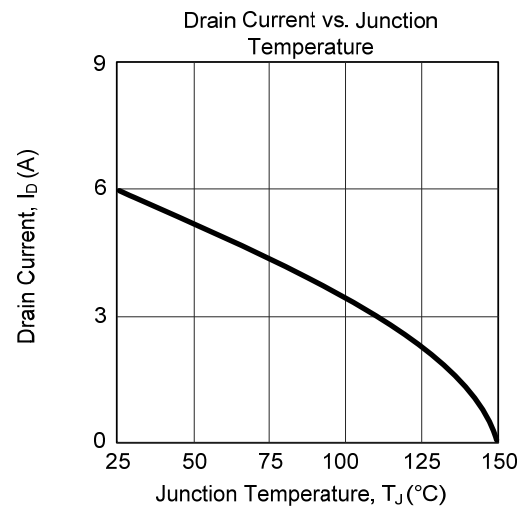
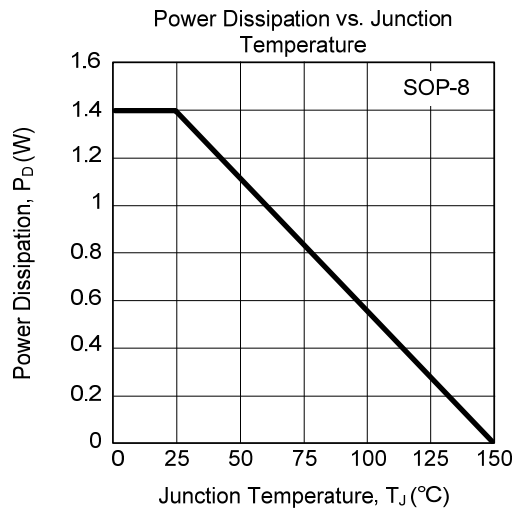


TYPICAL CHARACTERISTICS (Cont.)

P-CHANNEL



■ TYPICAL CHARACTERISTICS (Cont.)



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.